

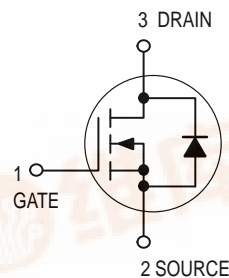


Low $r_{DS(on)}$ Small-Signal MOSFETs TMOS Single N-Channel Field Effect Transistors

Part of the GreenLine™ Portfolio of devices with energy-conserving traits.

These miniature surface mount MOSFETs utilize Motorola's High Cell Density, HDTMOS process. Low $r_{DS(on)}$ assures minimal power loss and conserves energy, making this device ideal for use in space sensitive power management circuitry. Typical applications are dc-dc converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

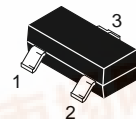
- Low $r_{DS(on)}$ Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space



MGSF1N02LT1

Motorola Preferred Device

N-CHANNEL
ENHANCEMENT-MODE
TMOS MOSFET



CASE 318-08, Style 21
SOT-23 (TO-236AB)

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

| Rating | Symbol | Value | Unit |
|---|-------------------|----------------|--------------------|
| Drain-to-Source Voltage | V_{DSS} | 20 | Vdc |
| Gate-to-Source Voltage — Continuous | V_{GS} | ± 20 | Vdc |
| Drain Current — Continuous @ $T_A = 25^\circ\text{C}$ — Pulsed Drain Current ($t_p \leq 10 \mu\text{s}$) | I_D I_{DM} | 750 2000 | mA |
| Total Power Dissipation @ $T_A = 25^\circ\text{C}$ | P_D | 225 | mW |
| Operating and Storage Temperature Range | T_J, T_{stg} | -55 to 150 | $^\circ\text{C}$ |
| Thermal Resistance — Junction-to-Ambient | $R_{\theta JA}$ | 625 | $^\circ\text{C/W}$ |
| Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds | T_L | 260 | $^\circ\text{C}$ |

ORDERING INFORMATION

| Device | Reel Size | Tape Width | Quantity |
|-------------|-----------|-------------------|----------|
| MGSF1N02LT1 | 7" | 8mm embossed tape | 3000 |
| MGSF1N02LT3 | 13" | 8mm embossed tape | 10,000 |

GreenLine is a trademark of Motorola, Inc.

HDTMOS is a trademark of Motorola, Inc. TMOS is a registered trademark of Motorola, Inc.

Thermal Clad is a trademark of the Bergquist Company.

Preferred devices are Motorola recommended choices for future use and best overall value.

MGSF1N02LT1

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

OFF CHARACTERISTICS

| | | | | | |
|---|---------------|--------|--------|-----------|-----------------|
| Drain-to-Source Breakdown Voltage ($V_{GS} = 0\text{ Vdc}$, $I_D = 10\text{ }\mu\text{Adc}$) | $V_{(BR)DSS}$ | 20 | — | — | Vdc |
| Zero Gate Voltage Drain Current ($V_{DS} = 16\text{ Vdc}$, $V_{GS} = 0\text{ Vdc}$) ($V_{DS} = 16\text{ Vdc}$, $V_{GS} = 0\text{ Vdc}$, $T_J = 125^\circ\text{C}$) | I_{DSS} | — — | — — | 1.0 10 | μAdc |
| Gate-Body Leakage Current ($V_{GS} = \pm 20\text{ Vdc}$, $V_{DS} = 0\text{ Vdc}$) | I_{GSS} | — | — | ± 100 | nAdc |

ON CHARACTERISTICS(1)

| | | | | | |
|---|--------------|--------|----------------|----------------|------|
| Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 250\text{ }\mu\text{Adc}$) | $V_{GS(th)}$ | 1.0 | 1.7 | 2.4 | Vdc |
| Static Drain-to-Source On-Resistance ($V_{GS} = 10\text{ Vdc}$, $I_D = 1.2\text{ Adc}$) ($V_{GS} = 4.5\text{ Vdc}$, $I_D = 1.0\text{ Adc}$) | $r_{DS(on)}$ | — — | 0.075 0.115 | 0.085 0.125 | Ohms |

DYNAMIC CHARACTERISTICS

| | | | | | | |
|----------------------|-------------------------------|-----------|---|-----|---|----|
| Input Capacitance | ($V_{DS} = 5.0\text{ Vdc}$) | C_{iss} | — | 100 | — | pF |
| Output Capacitance | ($V_{DS} = 5.0\text{ Vdc}$) | C_{oss} | — | 90 | — | |
| Transfer Capacitance | ($V_{DG} = 5.0\text{ Vdc}$) | C_{rss} | — | 40 | — | |

SWITCHING CHARACTERISTICS(2)

| | | | | | | |
|----------------------------|---|--------------|---|------|---|----|
| Turn-On Delay Time | (VDD = 15 Vdc, $I_D = 1.0\text{ Adc}$, $R_L = 50\text{ }\Omega$) | $t_{d(on)}$ | — | 2.5 | — | ns |
| Rise Time | | t_r | — | 1.0 | — | |
| Turn-Off Delay Time | | $t_{d(off)}$ | — | 16 | — | |
| Fall Time | | t_f | — | 8.0 | — | |
| Gate Charge (See Figure 6) | | Q_T | — | 6000 | — | pC |

SOURCE-DRAIN DIODE CHARACTERISTICS

| | | | | | |
|--------------------|----------|---|-----|------|---|
| Continuous Current | I_S | — | — | 0.6 | A |
| Pulsed Current | I_{SM} | — | — | 0.75 | |
| Forward Voltage(2) | V_{SD} | — | 0.8 | — | V |

(1) Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2\%$.

(2) Switching characteristics are independent of operating junction temperature.

TYPICAL ELECTRICAL CHARACTERISTICS

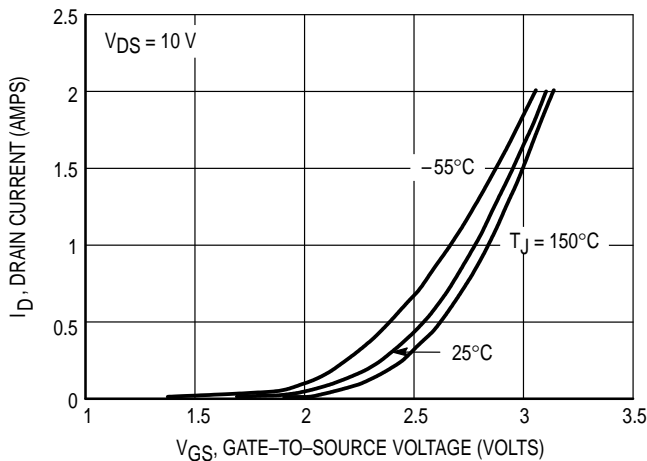


Figure 1. Transfer Characteristics

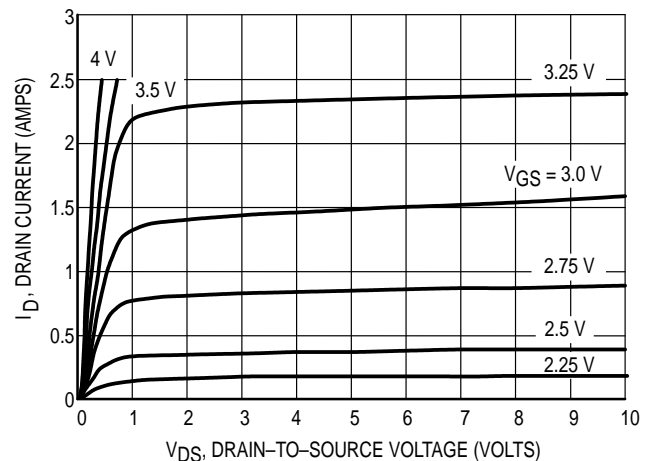


Figure 2. On-Region Characteristics

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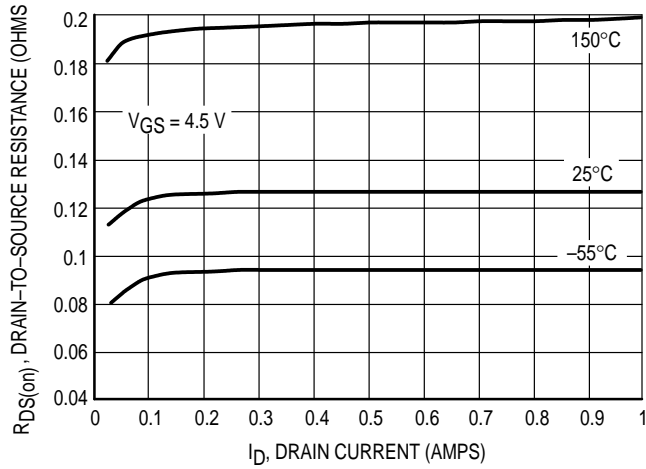


Figure 3. On-Resistance versus Drain Current

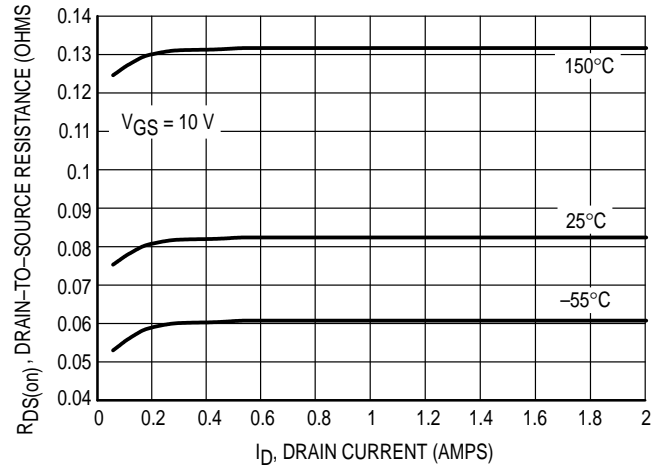


Figure 4. On-Resistance versus Drain Current

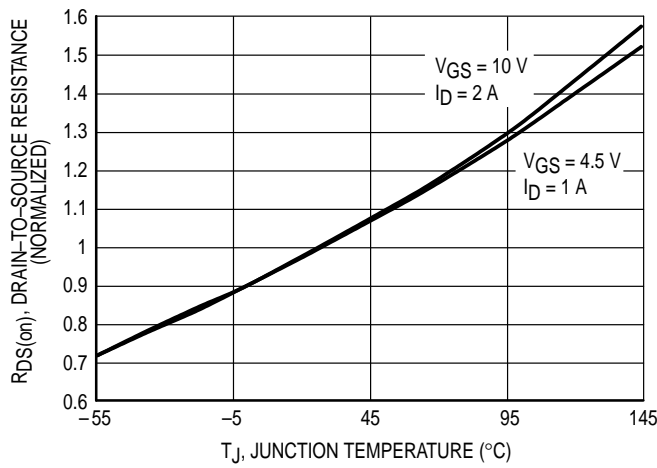


Figure 5. On-Resistance Variation with Temperature

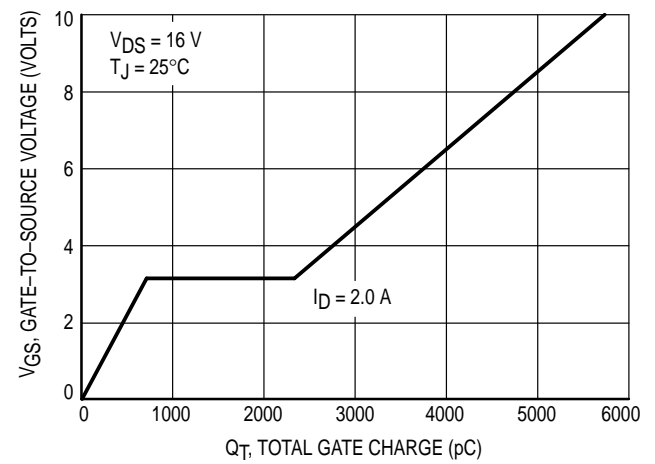


Figure 6. Gate Charge

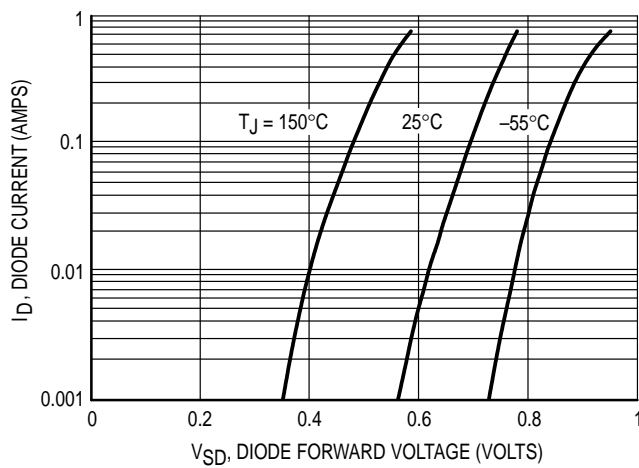


Figure 7. Body Diode Forward Voltage

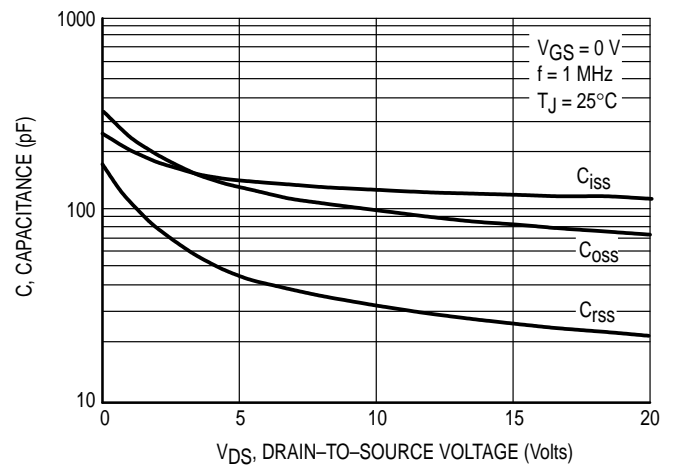


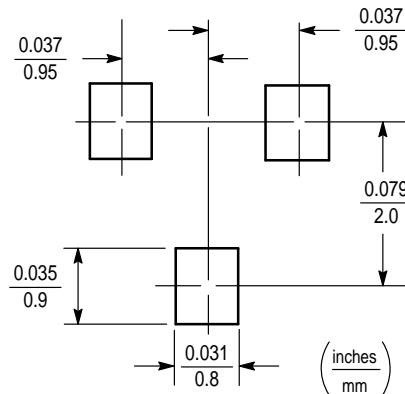
Figure 8. Capacitance

INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



SOT-23

SOT-23 POWER DISSIPATION

The power dissipation of the SOT-23 is a function of the drain pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by $T_{J(max)}$, the maximum rated junction temperature of the die, $R_{\theta JA}$, the thermal resistance from the device junction to ambient, and the operating temperature, T_A . Using the values provided on the data sheet for the SOT-23 package, P_D can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature T_A of 25°C, one can calculate the power dissipation of the device which in this case is 225 milliwatts.

$$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{556^\circ\text{C/W}} = 225 \text{ milliwatts}$$

The 556°C/W for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 225 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

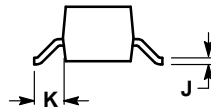
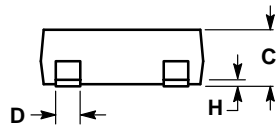
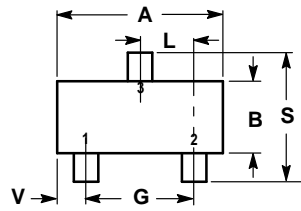
SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

PACKAGE DIMENSIONS



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.


| DIM | INCHES | | MILLIMETERS | |
|-----|--------|--------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.1102 | 0.1197 | 2.80 | 3.04 |
| B | 0.0472 | 0.0551 | 1.20 | 1.40 |
| C | 0.0350 | 0.0440 | 0.89 | 1.11 |
| D | 0.0150 | 0.0200 | 0.37 | 0.50 |
| E | 0.0701 | 0.0807 | 1.78 | 2.04 |
| F | 0.0005 | 0.0040 | 0.013 | 0.100 |
| G | 0.0034 | 0.0070 | 0.085 | 0.177 |
| H | 0.0180 | 0.0236 | 0.45 | 0.60 |
| I | 0.0350 | 0.0401 | 0.89 | 1.02 |
| J | 0.0830 | 0.0984 | 2.10 | 2.50 |
| K | 0.0177 | 0.0236 | 0.45 | 0.60 |

STYLE 21:

- PIN 1. GATE
- SOURCE
- DRAIN

CASE 318-08
ISSUE AE
SOT-23 (TO-236AB)

MGSF1N02LT1

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This device has a class 1 ESD rating.

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